

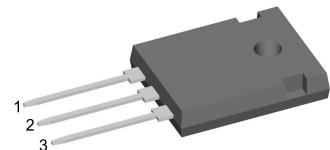
# Schottky Diode Gen 2

$V_{RRM}$  = 45 V  
 $I_{FAV}$  = 2x 40 A  
 $V_F$  = 0.69 V

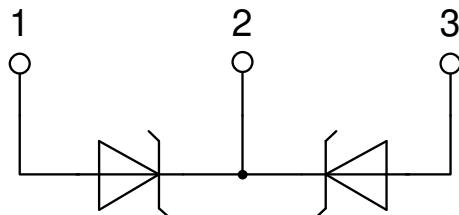
High Performance Schottky Diode  
 Low Loss and Soft Recovery  
 Common Cathode

**Part number**

**DSA80C45HB**



Backside: cathode



**Features / Advantages:**

- Very low  $V_F$
- Extremely low switching losses
- Low  $I_{rm}$  values
- Improved thermal behaviour
- High reliability circuit operation
- Low voltage peaks for reduced protection circuits
- Low noise switching

**Applications:**

- Rectifiers in switch mode power supplies (SMPS)
- Free wheeling diode in low voltage converters

**Package:** TO-247

- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0

**Disclaimer Notice**

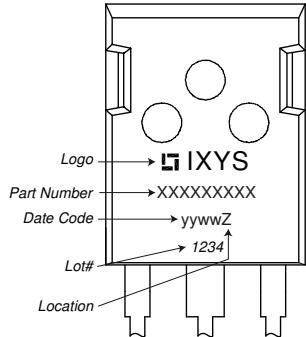
Information furnished is believed to be accurate and reliable. However, users should independently evaluate the suitability of and test each product selected for their own applications. Littelfuse products are not designed for, and may not be used in, all applications. Read complete Disclaimer Notice at [www.littelfuse.com/disclaimer-electronics](http://www.littelfuse.com/disclaimer-electronics).

**Schottky**

<b>Symbol</b>	<b>Definition</b>	<b>Conditions</b>	<b>Ratings</b>		
			<b>min.</b>	<b>typ.</b>	<b>max.</b>
<b>V<sub>RSM</sub></b>	max. non-repetitive reverse blocking voltage	T <sub>VJ</sub> = 25°C			45
<b>V<sub>RRM</sub></b>	max. repetitive reverse blocking voltage	T <sub>VJ</sub> = 25°C			45
<b>I<sub>R</sub></b>	reverse current, drain current	V <sub>R</sub> = 45 V V <sub>R</sub> = 45 V	T <sub>VJ</sub> = 25°C T <sub>VJ</sub> = 125°C		680 μA 7.5 mA
<b>V<sub>F</sub></b>	forward voltage drop	I <sub>F</sub> = 40 A I <sub>F</sub> = 80 A I <sub>F</sub> = 40 A I <sub>F</sub> = 80 A	T <sub>VJ</sub> = 25°C T <sub>VJ</sub> = 125°C		0.78 V 0.99 V 0.69 V 0.90 V
<b>I<sub>FAV</sub></b>	average forward current	T <sub>C</sub> = 150°C rectangular d = 0.5	T <sub>VJ</sub> = 175°C		40 A
<b>V<sub>F0</sub></b> <b>r<sub>F</sub></b>	threshold voltage } slope resistance } for power loss calculation only		T <sub>VJ</sub> = 175°C		0.43 V 5.1 mΩ
<b>R<sub>thJC</sub></b>	thermal resistance junction to case				0.7 K/W
<b>R<sub>thCH</sub></b>	thermal resistance case to heatsink			0.3	K/W
<b>P<sub>tot</sub></b>	total power dissipation	T <sub>C</sub> = 25°C			215 W
<b>I<sub>FSM</sub></b>	max. forward surge current	t = 10 ms; (50 Hz), sine; V <sub>R</sub> = 0 V	T <sub>VJ</sub> = 45°C		600 A
<b>C<sub>J</sub></b>	junction capacitance	V <sub>R</sub> = 5V f = 1 MHz	T <sub>VJ</sub> = 25°C	1.38	nF

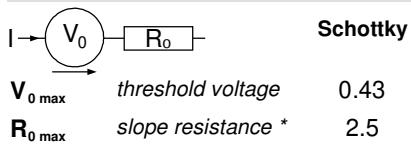
**Package TO-247**

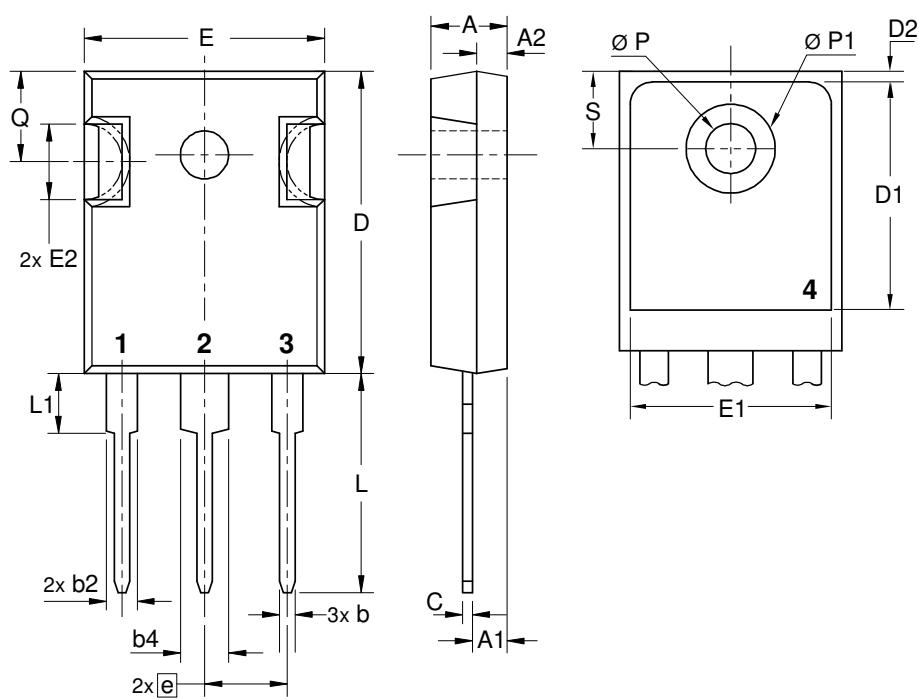
Symbol	Definition	Conditions	min.	typ.	max.	Unit
$I_{RMS}$	<i>RMS current</i>	per terminal <sup>1)</sup>			70	A
$T_{VJ}$	<i>virtual junction temperature</i>		-55		175	°C
$T_{op}$	<i>operation temperature</i>		-55		150	°C
$T_{stg}$	<i>storage temperature</i>		-55		150	°C
<b>Weight</b>				6		g
$M_d$	<i>mounting torque</i>		0.8		1.2	Nm
$F_c$	<i>mounting force with clip</i>		20		120	N

**Product Marking**

**Part description**

D = Diode  
S = Schottky Diode  
A = low VF  
80 = Current Rating [A]  
C = Common Cathode  
45 = Reverse Voltage [V]  
HB = TO-247AD (3)

Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	DSA80C45HB	DSA80C45HB	Tube	30	504890

**Equivalent Circuits for Simulation**
<sup>\* on die level</sup>
 $T_{VJ} = 175^\circ\text{C}$ 


**Outlines TO-247**


Sym.	Inches min. max.	Millimeter min. max.
A	0.185 0.209	4.70 5.30
A1	0.087 0.102	2.21 2.59
A2	0.059 0.098	1.50 2.49
D	0.819 0.845	20.79 21.45
E	0.610 0.640	15.48 16.24
E2	0.170 0.216	4.31 5.48
e	0.215 BSC	5.46 BSC
L	0.780 0.800	19.80 20.30
L1	- 0.177	- 4.49
Ø P	0.140 0.144	3.55 3.65
Q	0.212 0.244	5.38 6.19
S	0.242 BSC	6.14 BSC
b	0.039 0.055	0.99 1.40
b2	0.065 0.094	1.65 2.39
b4	0.102 0.135	2.59 3.43
c	0.015 0.035	0.38 0.89
D1	0.515 -	13.07 -
D2	0.020 0.053	0.51 1.35
E1	0.530 -	13.45 -
Ø P1	- 0.29	- 7.39

